



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## 30A02MH — PNP Epitaxial Planar Silicon Transistor Low-Frequency General-Purpose Amplifier Applications

### Applications

- Low-frequency Amplifier, high-speed switching small motor drive

### Features

- Large current capacity
- Low collector-to-emitter saturation voltage (resistance)  $R_{CE(sat)}$  typ=580mΩ[IC=0.7A, IB=35mA]
- Small ON-resistance (Ron)

### Specifications

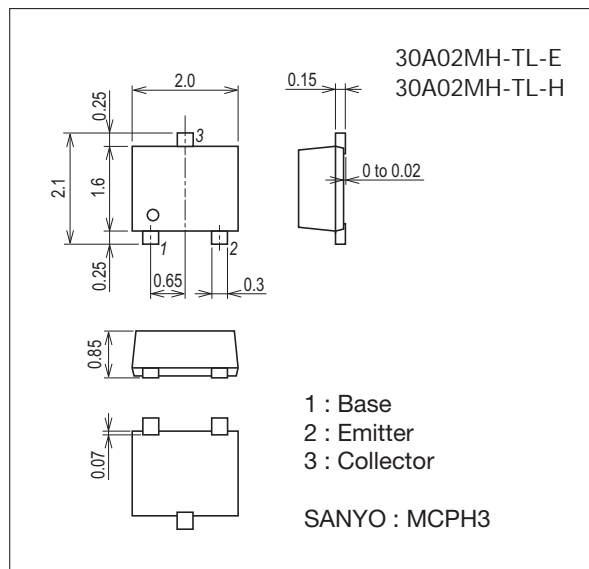
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-30	V
Collector-to-Emitter Voltage	VCEO		-30	V
Emitter-to-Base Voltage	VEBO		-5	V
Collector Current	IC		-700	mA
Collector Current (Pulse)	ICP		-1.4	A
Collector Dissipation	PC	When mounted on ceramic substrate (600mm <sup>2</sup> ×0.8mm)	600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Package Dimensions

unit : mm (typ)

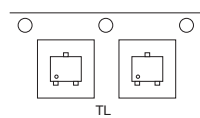
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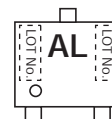
### Product & Package Information

- Package : MCPH3
- JEITA, JEDEC : SC-70, SOT-323
- Minimum Packing Quantity : 3,000 pcs./reel

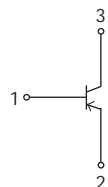
### Packing Type : TL



### Marking



### Electrical Connection

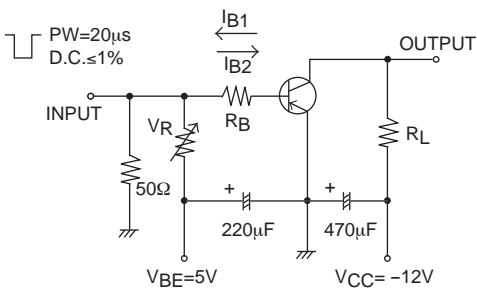


# 30A02MH

## Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = -30\text{V}, I_E = 0\text{A}$			-100	nA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = -4\text{V}, I_C = 0\text{A}$			-100	nA
DC Current Gain	$h_{FE}$	$V_{CE} = -2\text{V}, I_C = -10\text{mA}$	200		500	
Gain-Bandwidth Product	$f_T$	$V_{CE} = -10\text{V}, I_C = -50\text{mA}$		520		MHz
Output Capacitance	$C_{ob}$	$V_{CB} = -10\text{V}, f = 1\text{MHz}$		4.7		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -200\text{mA}, I_B = -10\text{mA}$		-110	-220	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -200\text{mA}, I_B = -10\text{mA}$		-0.9	-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu\text{A}, I_E = 0\text{A}$	-30			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1\text{mA}, R_{BE} = \infty$	-30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu\text{A}, I_C = 0\text{A}$	-5			V
Turn-ON Time	$t_{on}$	See specified Test Circuit.		35		ns
Storage Time	$t_{stg}$			125		ns
Fall Time	$t_f$			25		ns

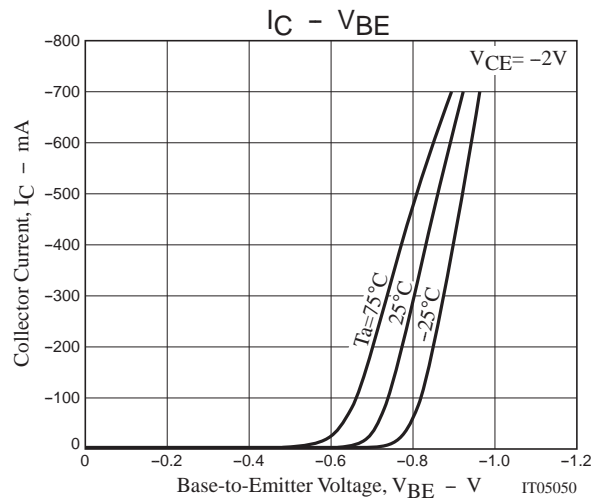
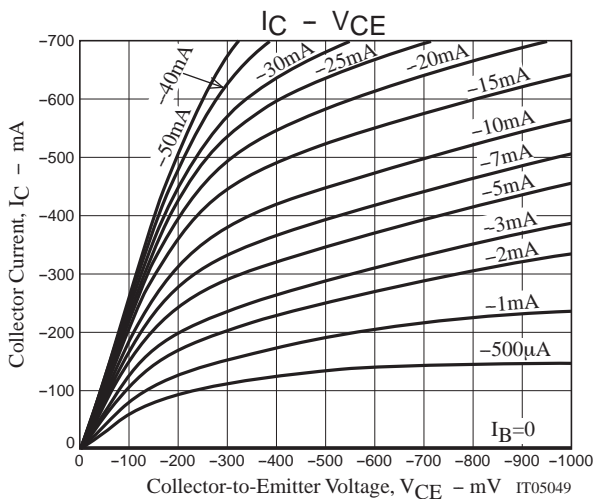
## Switching Time Test Circuit



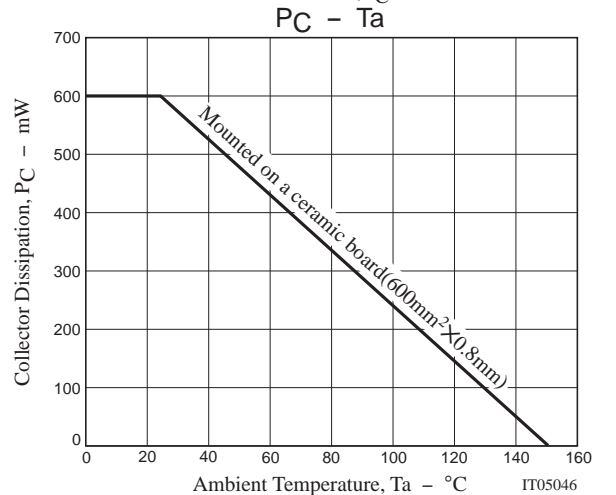
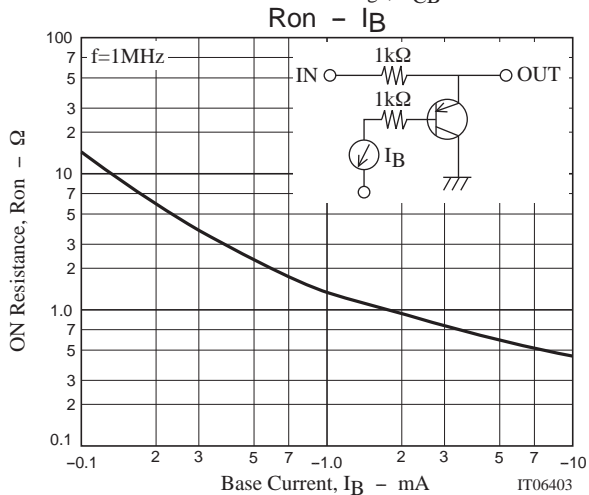
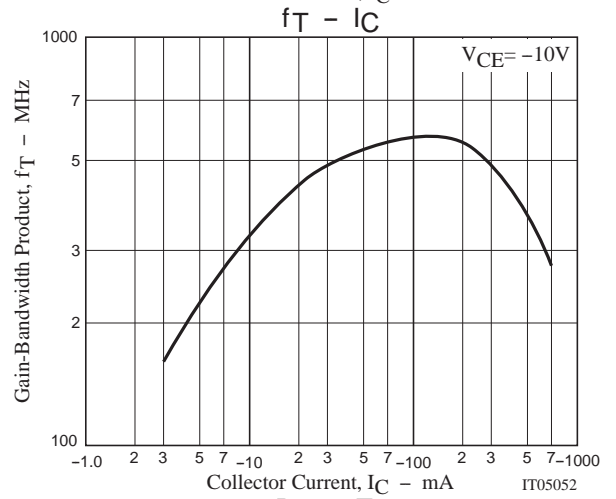
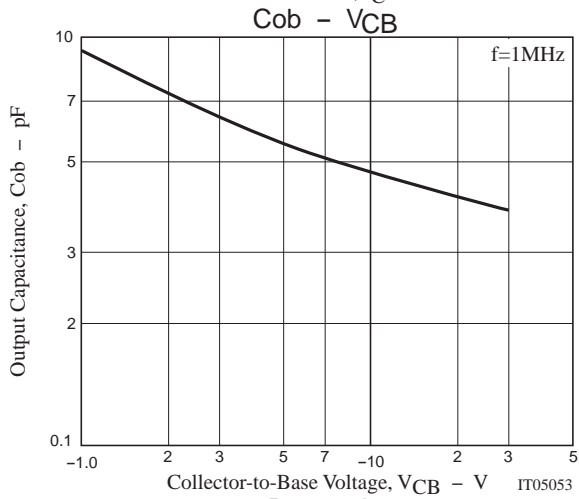
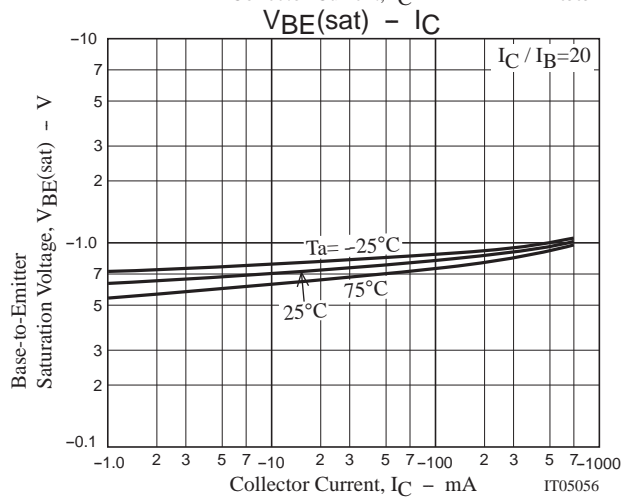
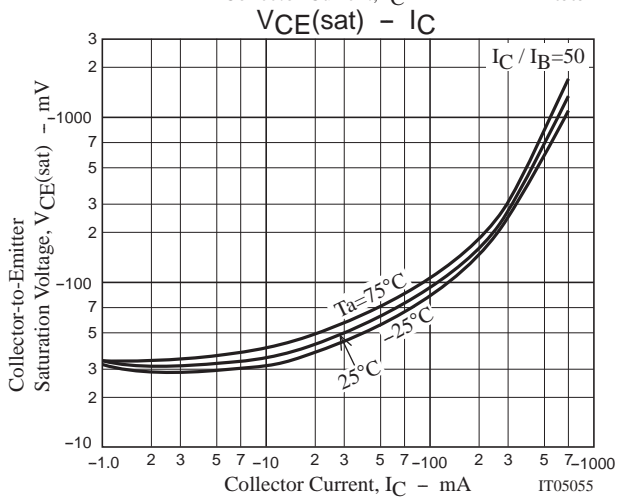
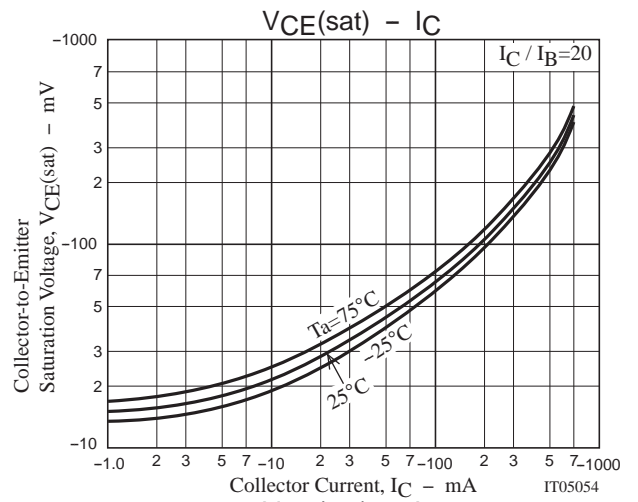
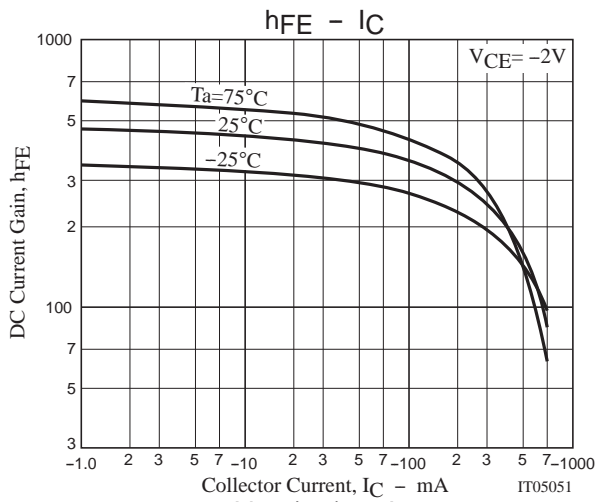
$$I_C = 20I_{B1} = -20I_{B2} = -300\text{mA}$$

## Ordering Information

Device	Package	Shipping	memo
30A02MH-TL-E	MCPH3	3,000pcs./reel	Pb Free
30A02MH-TL-H	MCPH3	3,000pcs./reel	Pb Free and Halogen Free



# 30A02MH



# 30A02MH

## Embossed Taping Specification

30A02MH-TL-E, 30A02MH-TL-H

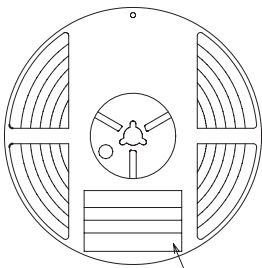
### 1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCPH3	MCPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label  
(unit: mm)

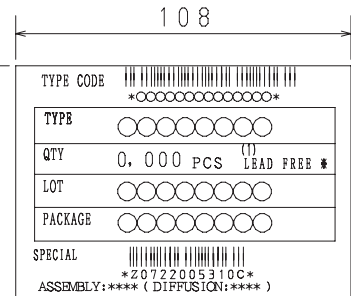
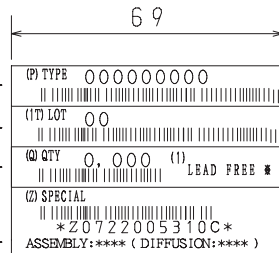
Outer box label  
It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

#### Packing method



Type No.  
LOT No.  
Quantity  
Origin

Reel label



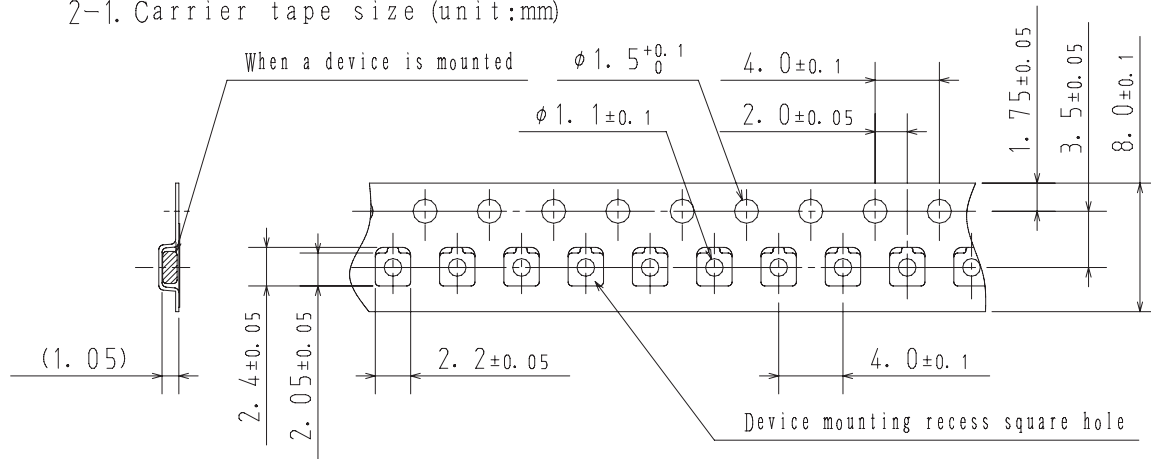
#### NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

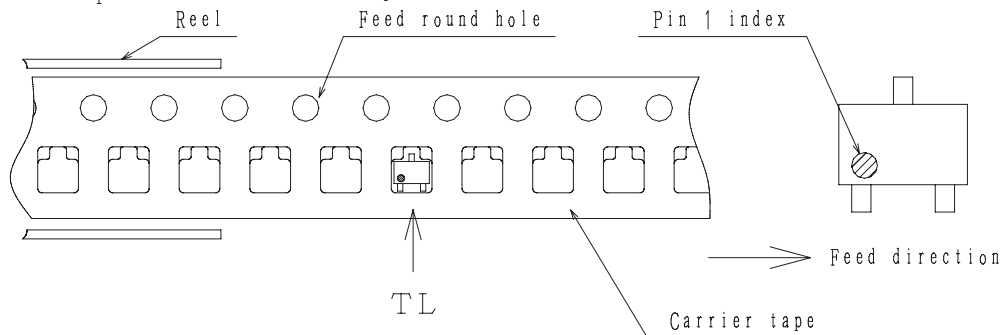
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

### 2. Taping configuration

#### 2-1. Carrier tape size (unit:mm)



#### 2-2. Device placement direction



Those with pin 1 index on the feed hole side.....TL

# 30A02MH

## Outline Drawing

30A02MH-TL-E, 30A02MH-TL-H



## Land Pattern Example



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- Техническая поддержка проекта;
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